





## Sensors for the CMS High Granularity Calorimeter

INSTR17 at BINP, Novosibirsk

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## The CMS HGCAL project

## Answer to HL-LHC challenges:

Pile-up: up to µ=200
 Otiming information valuable for mitigation

•Radiation exposure: up to 10<sup>16</sup> neq/cm<sup>2</sup>

Si well studied and under control for high fluences

replace entire endcap calorimeter, with a radiation-hard, fast timing, High Granularity Calorimeter (HGCAL)

## **Project details:**

- High granularity sampling calorimeter for particle flow (as studied by CALICE)
- Active development in
  - TDAQ
  - electronics architecture
  - particle flow reconstruction and physics performance
- TDR by end of 2017

Technical proposal: https://cds.cern.ch/record/2020886/files/LHCC-P-008.pdf

ECAL: Electromagnetic CALorimeter HCAL: Hadronic CALorimeter neq: 1 MeV neutron equivalent CALICE: CAlorimeter for Linear Collider Experiment TDR: Technical Design Repori TDAQ: Trigger and Data AcQuisition







## The CMS HGCAL layout

### **Active Elements:**

 Hexagonal Si sensor modules consisting of several 100 hexagonal sensor cells
 "Cassettes": multiple modules mounted on cooling plates with electronics and absorbers
 Scintillating tiles with SiPM readout in lowradiation regions

### **Key parameters:**

- 600 m<sup>2</sup> of silicon
  - hexagonal shape saves space on wafer
- Power at end of life ~60 kW per endcap
  25% due to leakage current
- CO<sub>2</sub>-cooled operation at -30°C

### Main components:

- •EE Si, Cu & CuW & Pb absorbers •28 layers: 25  $X_0$  + ~1.3  $\lambda$
- FH Si & scintillator, steel absorbers
  12 layers: ~3.5 λ
- BH Si & scintillator, steel absorbers
  11 layers: ~5.5 λ



SiPM: Si PhotoMultiplier
BH: Backing HCAL
FH: Front HCAL
EE: Endcap ECAL
ASIC: Application-Specific Integrated Circuit



## The HGCAL design



- Thinner Si sensors for high fluence regions  $\rightarrow$  better signal at high fluence
  - high- $\eta$  region: sensors with **120 \mum** active thickness
  - Iower-η regions: 200 μm & 300 μm active thickness
- Smaller cell size in central region  $\rightarrow$  less occupancy, less noise

## Single diode tests





### **Measured properties:**

- Bulk current → power consumption, noise
- Capacitance
- CCE with laser signal
- MIP studies with beta source
- Timing performance (test beam)
- Effects of annealing



See Esteban Curras Rivera's contribution for the IPRD16 conference for more details on the diode tests

## **First irradiation results:**

- Good signal at 1x10<sup>16</sup> neq/cm<sup>2</sup> within voltage range!
- Single MIP signal is resolvable from noise
- Intrinsic timing resolution of
  - < 50 ps for S/N > 10
  - ~20 ps for S > 20 MIPs

dd: deep diffusion	MIP: Minimum Ionizing Particle
FZ: Float Zone	MCP: Micro-Channel Plate
EPI: Epitaxial growth	S: Signal
CCE: Charge Collection Efficiency	N: Noise
HPK: Hamamatsu	





**Detector optimization ongoing:** 

- Wafer size (6" or 8")
- Contact pad layout for wire bonding (e.g. jumper cells)
- Sensor type (n-in-p or p-in-n)
- Interpad distance

### **Ongoing activities:**

16.5 cm

- (Automated) sensor tests
- Design studies for TDR
- p-stop layout validation
- Radiation testing

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## Modules for HGCAL





## Full wafer measurements

6" 135 pad HPK sensors measured at FNAL

### Leakage current Capacitance Lower leakage currents Mouse bites & calibration cells show Higher leakage currents in the calibration cells in the edge region lower capacitances than full cells (smaller size) [Yu] 2.5 I test capacity guard ring value scaled by 0.5 test capacity 2 value scaled by 0.5 scaled by 0.1 test canacity Ц Ц test capacity 3 value scaled by 0.1 1.5 0.5 pad numbers according to probe card values for U = 300.0 V pad numbers according to probe card values for U = 1000.0 V

•Detector conditions: all cells biased by probe card

- Excellent performance of the tested wafers
  - •behavior as expected for IV and CV measurements
  - •no breakdown until 1000 V bias voltage observed among all tested sensors

For more information on the probe card, see backup



## 2016 beam tests





- Cassettes consist of
  - one ore two modules mounted
  - ${\ensuremath{ \bullet}}$  on absorber plates with electronics and cooling
- Can be easily stacked and removed from frame
- Mechanics as well as DAQ is designed scalable



## The test beam setup

### **FNAL**

- Up to 16 HGCAL modules tested
- e<sup>-</sup> beam at 4-32 GeV
- Protons at 120 GeV
- $\bullet$  0.6-15 X<sub>0</sub> absorber configuration

### CERN

- Up to 8 HGCAL modules tested
- π/µ at 125 GeV
- e<sup>-</sup> beam at 20-250 GeV
- ${old O}$  6-15  $X_{_0}$  and 5-27  $X_{_0}$  absorber configurations





Electron showers passing through 8 layers (27  $X_0$ )

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## Test beam results



## **Results**

- Energy response is linear
- Series of beam tests planned for 2017 Shower profile and energy resolution agree well with simulation
- $\circ$  dE/dx weighting improves energy resolution by ~20%

TB: Test Beam FTFP BERT EMM: A fast electromagnetic shower model optimised for CMS HCAL





# Conclusions

- •Good progress on the way to a full HGCAL
- •Series of beam tests to understand and demonstrate detector performance
- Sensor testing ongoing
- •Potential timing precision of < 50 ps
- •Main design decisions in the coming months leading to TDR end of 2017

## Thank you for your attention!

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## Backup - The HGCAL schedule





## Backup - Full wafer test setup



• Bias all sensor cells during the tests at the same time for realistic test conditions

- contact and bias all cells at the same time using probe card
- spring-loaded pins (pogo pins) for uniform contact over whole plane
- Depending on the sensor layout, test 128 up to 512 channels
- Newly designed switching matrix placed as a plugin card on top of the probe card

GPIB: General Purpose Interface Bus